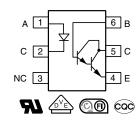


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Vishay Semiconductors

Optocoupler, Photodarlington Output, High Gain, with Base Connection





FEATURES

- Isolation test voltage: 5300 V_{RMS}
- Coupling capacitance, 0.5 pF
- Material categorization:
 For definitions of compliance please see www.vishav.com/doc?99912





AGENCY APPROVALS

- UL1577, file no. E52744 system code J
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- FIMKO EN60065, EN60950-1
- CQC: GB8898

DESCRIPTION

The H11B1, H11B2, H11B3 are industry standard optocouplers, consisting of a gallium arsenide infrared LED and a silicon photodarlington.

ORDERING INFORMATION			
H 1 1 B PART NUMBER	# - X	0 0 # PACKAGE OPTION	7.62 mm Option 7 Option 9
AGENCY CERTIFIED/PACKAGE		CTR (%)	
UL, FIMKO, CQC	> 500	> 200	> 100
DIP-6	H11B1	H11B1 H11B2	
SMD-6, option 7	H11B1-X007T ⁽¹⁾	-	-
SMD-6, option 9	H11B1-X009	H11B2-X009T ⁽¹⁾	-
UL, FIMKO, CQC, VDE	> 500	> 200	> 100
SMD-6, option 7	H11B1-X017	-	-

Notes

- Additional options may be possible, please contact sales office.
- (1) Also available in tubes, no "T" in the end.

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT				•		
Reverse voltage		V _R	3	V		
Forward continuous current		I _F	60	mA		
Power dissipation		P _{diss}	100	mW		
Derate linearly from 25 °C			1.33	mW/°C		
OUTPUT						
Collector emitter breakdown voltage		BV _{CEO}	25	V		
Emitter collector breakdown voltage		BV _{ECO}	7	V		
Collector base breakdown voltage		BV _{CBO}	30	V		
Collector current (continuous)		I _C	100	mA		
Power dissipation		P _{diss}	150	mW		
Derate linearly from 25 °C			2	mW/°C		



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
COUPLER							
Isolation test voltage between emitter and detector		V _{ISO}	5300	V_{RMS}			
Creepage distance			≥ 7	mm			
Clearance distance			≥ 7	mm			
Comparative tracking index per DIN IEC 112/VDE 0303, part 1		СТІ	175				
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω			
	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω			
Total package dissipation (LED plus detector)		P _{tot}	260	mW			
Derate linearly from 25 °C			3.5	mW/°C			
Storage temperature		T _{stg}	- 55 to + 150	°C			
Operating temperature		T _{amb}	- 55 to + 100	°C			
Lead soldering time at 260 °C			10	s			

Note

• Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
	I _E = 50 mA	H11B1	V_{F}		1.1	1.5	V
Forward voltage	IF = 30 IIIA	H11B2	V_{F}		1.1	1.5	V
	I _F = 10 mA	H11B3	V_{F}		1.1	1.5	V
Reverse current	V _R = 3 V		I _R			10	μΑ
Junction capacitance	$V_F = 0 V, f = 1 MHz$		C _j		50		pF
OUTPUT							
Collector emitter breakdown voltage	$I_C = 1 \text{ mA}, I_F = 0 \text{ mA}$		BV _{CEO}	30			V
Emitter collector breakdown voltage	$I_E = 100 \mu A, I_F = 0 \text{ mA}$		BV _{ECO}	7			V
Collector base breakdown voltage	$I_C = 100 \mu A$, $I_F = 0 mA$		BV _{CBO}	30			V
Collector emitter leakage current	$V_{CE} = 10 \text{ V}, I_F = 0 \text{ mA}$		I _{CEO}			100	nA
COUPLER							
Saturation voltage collector-emitter	$I_F = 1 \text{ mA}, I_C = 1 \text{ mA}$		V _{CEsat}			1	V
Capacitance (input to output)			C _{IO}		0.5		pF

Note

Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
DC current transfer ratio	V _{CE} = 5 V, I _F = 1 mA	H11B1	CTR _{DC}	500			%
		H11B2	CTR _{DC}	200			%
		H11B3	CTR _{DC}	100			%

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION SYMBOL MIN. TYP. MAX. UNI						
Switching times	I_F = 5 mA, V_{CE} = 10 V, R_L = 100 Ω	t _{on}		5		μs	
		t _{off}		30		μs	

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

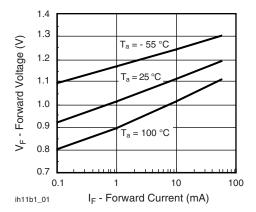


Fig. 1 - Forward Voltage vs. Forward Current

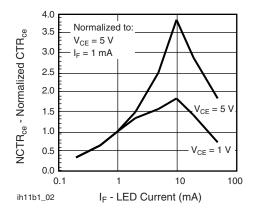


Fig. 2 - Normalized Non-Saturated and Saturated CTR_{CE} vs. LED Current

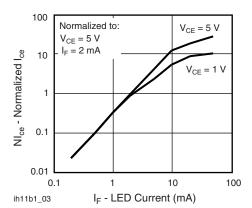


Fig. 3 - Normalized Non-Saturated and Saturated I_{CE} vs. LED Current

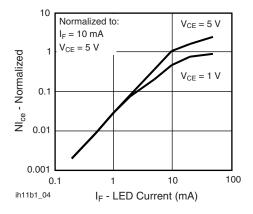


Fig. 4 - Normalized Non-Saturated and Saturated Collector Emitter Current vs. LED Current

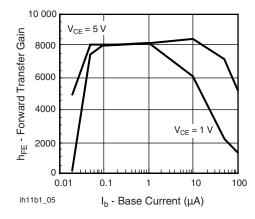


Fig. 5 - Non-Saturated and Saturated $h_{\text{FE}}\ \text{vs.}$ Base Current

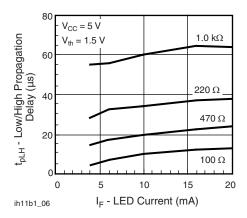


Fig. 6 - Low to High Propagation Delay vs. Collector Load Resistance and LED Current

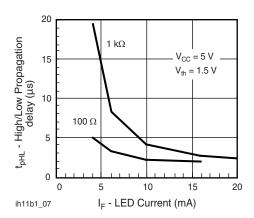
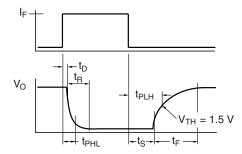


Fig. 7 - High to Low Propagation Delay vs. Collector Load Resistance and LED Current



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Fig. 8 - Switching Waveform

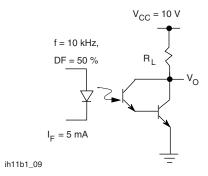
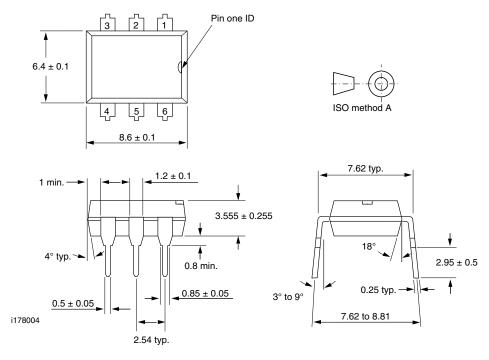
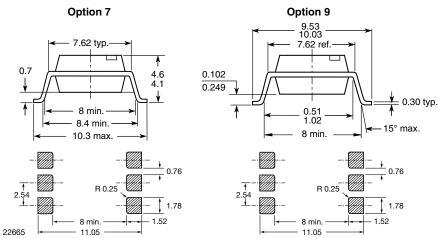


Fig. 9 - Switching Schematic

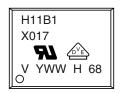
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PACKAGE DIMENSIONS in millimeters





PACKAGE MARKING



Notes

- Only options 1, 7, and 9 are reflected in the package marking.
- The VDE logo is only marked on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking.



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